

AT45DB081E-SSHN2B-T

Data Sheet

8Mbit, 1.7 V to 3.6 V Range SPI Serial Flash Memory

Manufacturers	Renesas Technology Corp
Package/Case	
Product Type	Memory
RoHS	
Lifecycle	



Images are for reference only

Please submit RFQ for AT45DB081E-SSHN2B-T or <u>Email to us: sales@ovaga.com</u> We will contact you in 12 hours.

General Description

Features

Includes a controllable R/W SRAM buffer for maximum flexibility

Standard block architecture with added 256-byte page erase for energy efficient Data Logging

Byte-write provides Serial EEPROM functionality in a Serial NOR Flash device

Ultra-deep power down operates at >400nA

Extended Vcc operation allows the system memory to operate over the entire voltage range

Comprehensive security and unique ID features protect the device from outside tampering



Related Products



AT45DB641E-SHN2B-T Renesas Technology Corp SOIC-8



AT25DF321A-MH-T Renesas Technology Corp UDFN-8



AT45DB081E-SSHN-B

Renesas Technology Corp SOIC-8



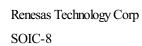
AT45DB041E-SHN-T Renesas Technology Corp SOIC-8



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AT45DB081E-SHN-T

AT45DB021E-SHN-B

Renesas Technology Corp

AT45DB161E-SHD-B

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AT25DF321A-SH-T

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